Panasonic

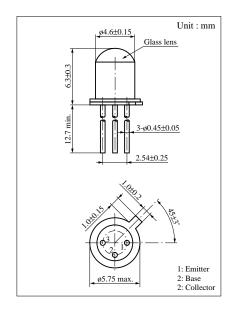
PNZ102 (PN102)

Silicon NPN Phototransistor

For optical control systems

Features

- High sensitivity
- Wide spectral sensitivity, suited for detecting GaAs LEDs
- Low dark current : $I_{CEO} = 5 \text{ nA (typ.)}$
- Fast response : t_r , $t_f = 3 \mu s$ (typ.)
- Base pin for easy circuit design
- TO-18 standard type package



■ Absolute Maximum Ratings (Ta = 25°C)

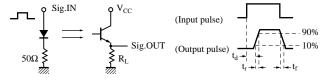
| Parameter | Symbol | Ratings | Unit | |
|-------------------------------|------------------|-------------|------|--|
| Collector to emitter voltage | V _{CEO} | 30 | V | |
| Collector to base voltage | V_{CBO} | 40 | V | |
| Emitter to collector voltage | V _{ECO} | 5 | V | |
| Emitter to base voltage | V_{EBO} | 5 | V | |
| Collector current | I_C | 50 | mA | |
| Collector power dissipation | P _C | 150 | mW | |
| Operating ambient temperature | T _{opr} | -25 to +85 | °C | |
| Storage temperature | T_{stg} | -30 to +100 | °C | |

■ Electro-Optical Characteristics (Ta = 25°C)

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|------------------------------|------------------------|--|-----|-----|-----|------|
| Dark current | I_{CEO} | $V_{CE} = 10V$ | | 5 | 300 | nA |
| Collector photo current | I _{CE(L)} | $V_{CE} = 10V, L = 100 lx^{*1}$ | 1.5 | 3.5 | | mA |
| Peak sensitivity wave length | λ_{P} | $V_{CE} = 10V$ | | 800 | | nm |
| Acceptance half angle | θ | Measured from the optical axis to the half power point | | 10 | | deg. |
| Response time | t_r, t_f^{*2} | $V_{CC} = 10V, I_{CE(L)} = 5mA, R_L = 100\Omega$ | | 3 | | μs |
| Collector saturation voltage | V _{CE(sat)} | $I_{CE(L)} = 1 \text{mA}, L = 500 \text{ lx}^{*1}$ | | 0.2 | 0.4 | V |

^{*1} Measurements were made using a tungsten lamp (color temperature T = 2856K) as a light source.

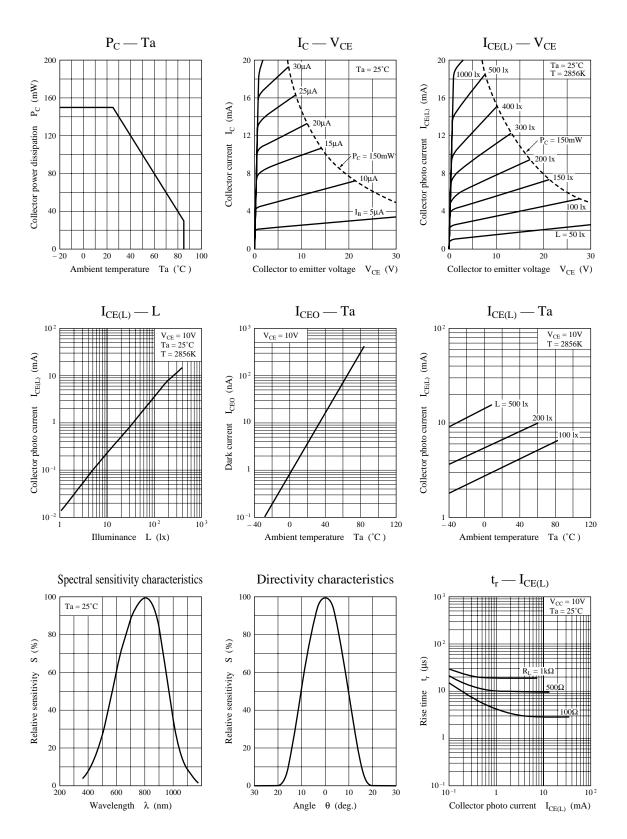
^{*2} Switching time measurement circuit



- t_d: Delay time
- t_r: Rise time (Time required for the collector photo current to increase from 10% to 90% of its final value)
- t_f: Fall time (Time required for the collector photo current to decrease from 90% to 10% of its initial value)

Note) The part number in the parenthesis shows conventional part number.

Phototransistors PNZ102



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